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PATENT

Atty. Docket: 10191/1466

GROUP 1700

N THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant

Volker BECKER, et al.

Serial No.

09/581,663

Filed

August 3, 2000

For

METHOD FOR PROCESSING SILICON

BY ETCHING PROCESSES

Group Art Unit

1746

Examiner

S. AHMED

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SUPPLEMENTAL AMENDMENT AFTER FINAL REJECTION UNDER 37 C.F.R. § 1.116

SIR:

In response to the Final Office Action dated July 5, 2002, please amend the above-identified application, as set forth below. Entry of the amendment is requested since it raises no new issue and merely puts an objected-to claim in condition for allowance.

IN THE CLAIMS:

Please amend claims 53 and 63 as follows:

53. (Amended) A method for etching a silicon layered body, which has a first silicon layer (15) that is provided with an etching mask (10) for defining lateral